

Exhibition at the First EV & HEV Drive System Technology Expo (EV Japan)

The First EV & HEV Drive System Technology Expo (EV Japan) is to be held at Tokyo Big Sight from January 20th (Wednesday) through 22nd (Friday), 2010.

Fuji Electric Semiconductors shall be introducing its highly reliable IGBT module and IPM for hybrid vehicles, advanced pressure sensor, power IC, and power MOSFET, etc. that contribute both to the environment and safety through the application of semiconductor technology accumulated for industrial purposes under the theme “Car Electronics Solutions: Contributing to the Environment, Safety and Comfort”.

We look forward to your participation despite your doubtless busy schedule.

Outline

Date: January 20th (Wednesday) - 22nd (Friday), 2010

Time: 10:00 - 18:00 (closing at 17:00 on Friday, 22nd)

Venue: West Hall 2, Tokyo Big Sight

Booth No.: 4-44

Organizer: Reed Exhibitions Japan Ltd.

Main exhibits:

1. IGBT module for Hybrid vehicles
2. Power IC
3. Power MOSFET
4. Pressure sensor

Please apply for invitations for the exhibition via our sales representatives or the “[Homepage for The First EV & HEV Drive System Technology Expo \(EV Japan\)](#)”.